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Self-Protected High Side Driver with Temperature and Current Limit

NCV8450, NCV8450A

The NCV8450/A is a fully protected High-Side Smart Discrete device with a typical $R_{DS(on)}$ of 1.0 Ω and an internal current limit of 0.8 A typical. The device can switch a wide variety of resistive, inductive, and capacitive loads.

Features

- Short Circuit Protection
- Thermal Shutdown with Automatic Restart
- Overvoltage Protection
- Integrated Clamp for Inductive Switching
- Loss of Ground Protection
- ESD Protection
- Slew Rate Control for Low EMI
- Very Low Standby Current
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Automotive
- Industrial

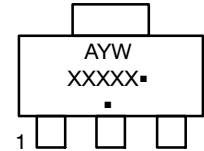
PRODUCT SUMMARY

Symbol	Characteristics	Value	Unit
V_{IN_CL}	Overvoltage Protection	54	V
$V_{D(on)}$	Operation Voltage	4.5 – 45	V
R_{on}	On-State Resistance	1.0	Ω



SOT-223
(TO-261)
CASE 318E

MARKING DIAGRAM



XXXXX = V8450 or 8450A
 A = Assembly Location
 Y = Year
 W = Work Week
 ▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

NCV8450, NCV8450A

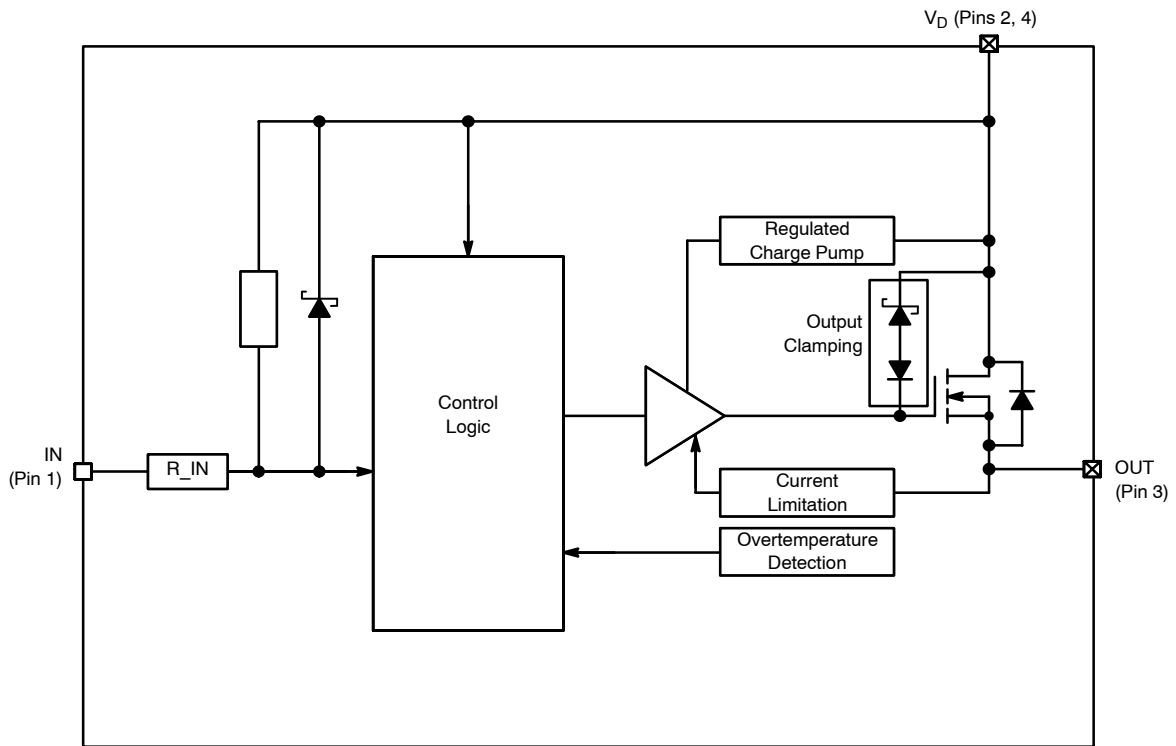


Figure 1. Block Diagram

PACKAGE PIN DESCRIPTION

Pin #	Symbol	Description
1	IN	Control Input, Active Low
2	V_D	Supply Voltage
3	OUT	Output
4	V_D	Supply Voltage

NCV8450, NCV8450A

MAXIMUM RATINGS

Rating	Symbol	Value		Unit
		Min	Max	
DC Supply Voltage (Note 1)	V_D	-16	45	V
Load Dump Protection ($R_I = 2 \Omega$, $t_d = 400 \text{ ms}$, $V_{IN} = 0, 10 \text{ V}$, $I_L = 150 \text{ mA}$, $V_{bb} = 13.5 \text{ V}$)	V_{LoadDump}		85	V
Input Current	I_{in}	-15	15	mA
Output Current (Note 1)	I_{out}		Internally Limited	A
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ (Note 2) @ $T_A = 25^\circ\text{C}$ (Note 3)	P_D		1.13 1.60	W
Electrostatic Discharge (Note 4) (Human Body Model (HBM) 100 pF/1500 Ω) Input All other			1 5	kV
Single Pulse Inductive Load Switching Energy (Note 4) ($V_{DD} = 13.5 \text{ V}$, $I = 465 \text{ mA}$, $L = 200 \text{ mH}$, $T_{J\text{Start}} = 150^\circ\text{C}$)	E_{AS}		29	mJ
Operating Junction Temperature	T_J	-40	+150	$^\circ\text{C}$
Storage Temperature	T_{storage}	-55	+150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Reverse Output current has to be limited by the load to stay within absolute maximum ratings and thermal performance.
- Minimum Pad.
- 1 in square pad size, FR-4, 1 oz Cu.
- Not subjected to production testing.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max Value	Unit
Thermal Resistance (Note 5) Junction-to-Ambient (Note 2) Junction-to-Ambient (Note 3)	$R_{\theta JA}$ $R_{\theta JA}$	110 78.3	K/W

- Not subjected to production testing.

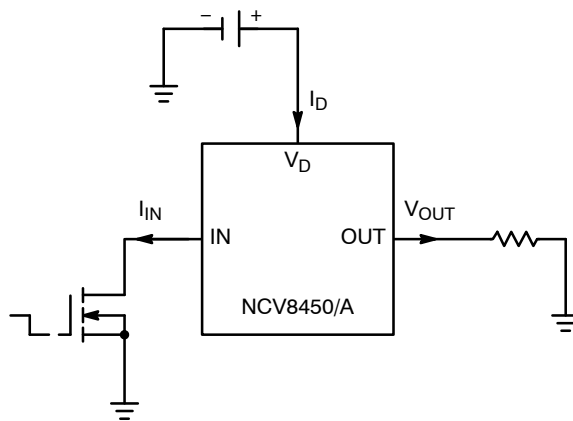


Figure 2. Applications Test Circuit

NCV8450, NCV8450A

ELECTRICAL CHARACTERISTICS ($6 \leq V_D \leq 45 \text{ V}$; $-40^\circ\text{C} < T_J < 150^\circ\text{C}$ unless otherwise specified)

Rating	Symbol	Conditions	Value			Unit
			Min	Typ	Max	

OUTPUT CHARACTERISTICS

Operating Supply Voltage	V_{SUPPLY}		4.5	-	45	V
On Resistance (Pin 1 Connected to GND)	R_{ON}	$T_J = 25^\circ\text{C}$, $I_{\text{OUT}} = 150 \text{ mA}$, $V_D = 7 \text{ V} - 45 \text{ V}$ $T_J = 150^\circ\text{C}$, $I_{\text{OUT}} = 150 \text{ mA}$, $V_D = 7 \text{ V} - 45 \text{ V}$ (Note 6) $T_J = 25^\circ\text{C}$, $I_{\text{OUT}} = 150 \text{ mA}$, $V_D = 6 \text{ V}$		1.0 1.4	2 3	Ω
Standby Current (Pin 1 Open)	I_D	$V_D \leq 20 \text{ V}$ $V_D > 20 \text{ V}$		0.6	10 100	μA

INPUT CHARACTERISTICS

Input Current – Off State	$I_{\text{IN_OFF}}$	$V_{\text{OUT}} \leq 0.1 \text{ V}$, $R_L = 270 \Omega$, $T_J = 25^\circ\text{C}$ $V_{\text{OUT}} \leq 0.1 \text{ V}$, $R_L = 270 \Omega$, $T_J = 150^\circ\text{C}$ (Note 6)	-50 -40			μA
Input Current – On State (Pin 1 Grounded)	$I_{\text{IN_ON}}$			1.5	3	mA
Input Resistance (Note 6)	R_{IN}			1		k Ω

SWITCHING CHARACTERISTICS

Turn-On Time (Note 7) ($V_{\text{IN}} = V_D$ to 0 V) to 90% V_{OUT}	t_{ON}	$R_L = 270 \Omega$ (Note 6) $V_D = 13.5 \text{ V}$, $R_L = 270 \Omega$, $T_J = 25^\circ\text{C}$		30	125 100	μs
Turn-Off Time (Note 7) ($V_{\text{IN}} = 0 \text{ V}$ to V_D) to 10% V_{OUT}	t_{OFF}	$R_L = 270 \Omega$ (Note 6) $V_D = 13.5 \text{ V}$, $R_L = 270 \Omega$, $T_J = 25^\circ\text{C}$		60	175 150	μs
Slew Rate On (Note 7) ($V_{\text{IN}} = V_D$ to 0V) 10% to 30% V_{OUT}	dV/dt_{ON}	$R_L = 270 \Omega$ (Note 6) $V_D = 13.5 \text{ V}$, $R_L = 270 \Omega$, $T_J = 25^\circ\text{C}$		0.7	4 4	V/ μs
Slew Rate Off (Note 7) ($V_{\text{IN}} = 0 \text{ V}$ to V_D) 70% to 40% V_{OUT}	dV/dt_{OFF}	$R_L = 270 \Omega$ (Note 6) $V_D = 13.5 \text{ V}$, $R_L = 270 \Omega$, $T_J = 25^\circ\text{C}$		0.9	4 4	V/ μs

OUTPUT DIODE CHARACTERISTICS (Note 6)

Drain-Source Diode Voltage	V_F	$I_{\text{OUT}} = -0.2 \text{ A}$		0.6		V
Continuous Reverse Drain Current	I_S	$T_J = 25^\circ\text{C}$			0.2	A

PROTECTION FUNCTIONS (Note 8)

Temperature Shutdown (Note 6)	T_{SD}		150	175	-	$^\circ\text{C}$
Temperature Shutdown Hysteresis (Note 6)	$T_{\text{SD_HYST}}$			5		$^\circ\text{C}$
Output Current Limit	I_{LIM}	$T_J = -40^\circ\text{C}$, $V_D = 13.5 \text{ V}$, $t_m = 100 \mu\text{s}$ (Note 6) $T_J = 25^\circ\text{C}$, $V_D = 13.5 \text{ V}$, $t_m = 100 \mu\text{s}$ $T_J = 150^\circ\text{C}$, $V_D = 13.5 \text{ V}$, $t_m = 100 \mu\text{s}$ (Note 6)	0.5	0.8	1.5	A
Output Clamp Voltage (Inductive Load Switch Off) At $V_{\text{OUT}} = V_D - V_{\text{CLAMP}}$	V_{CLAMP}	$I_{\text{OUT}} = 4 \text{ mA}$	45	52		V
Overvoltage Protection	$V_{\text{IN_CL}}$	$I_{\text{CLAMP}} = 4 \text{ mA}$	50	54		V

6. Not subjected to production testing

7. Only valid with high input slew rates

8. Protection functions are not designed for continuous repetitive operation and are considered outside normal operating range

TYPICAL CHARACTERISTIC CURVES

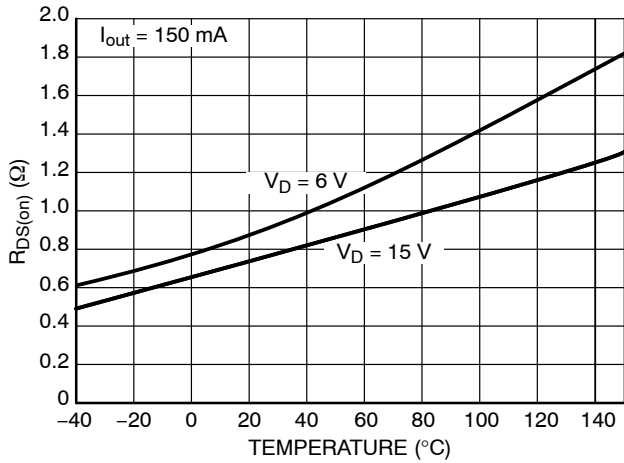


Figure 3. $R_{DS(on)}$ vs. Temperature

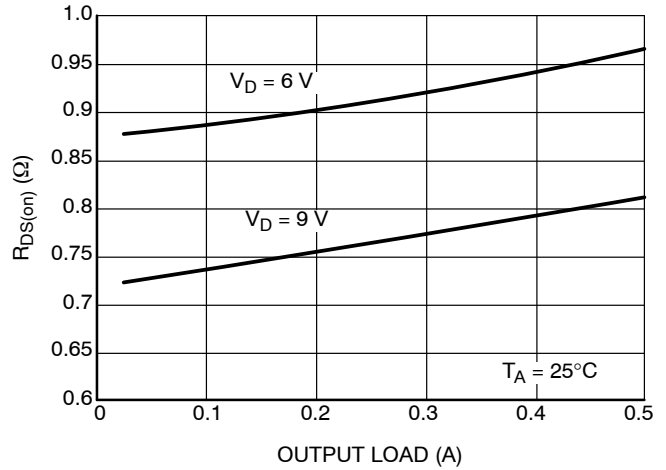


Figure 4. $R_{DS(on)}$ vs. Output Load

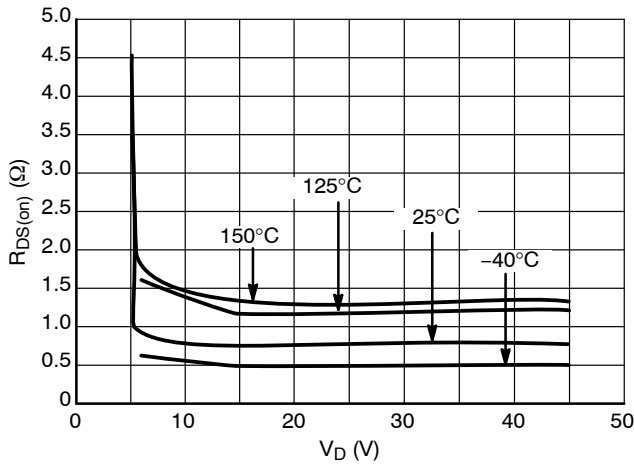


Figure 5. $R_{DS(on)}$ vs. V_D

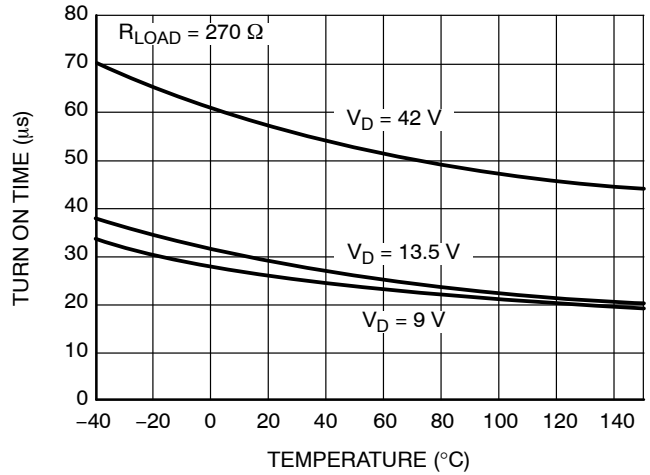


Figure 6. Turn On Time vs. Temperature

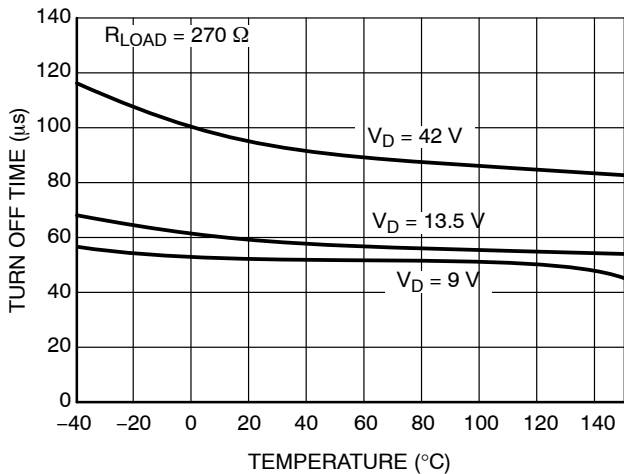


Figure 7. Turn Off Time vs. Temperature

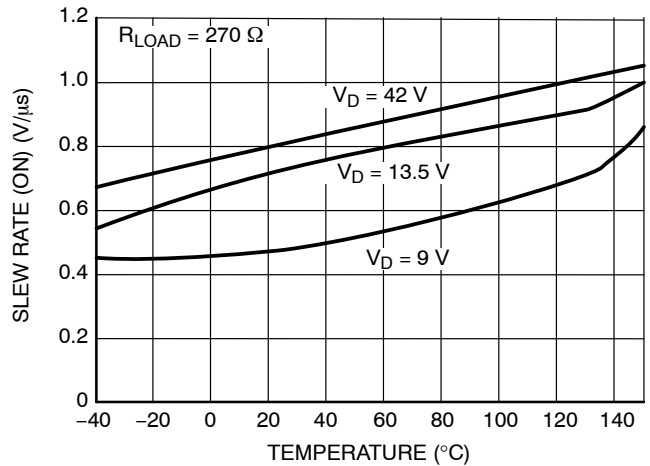


Figure 8. Slew Rate (ON) vs. Temperature

TYPICAL CHARACTERISTIC CURVES

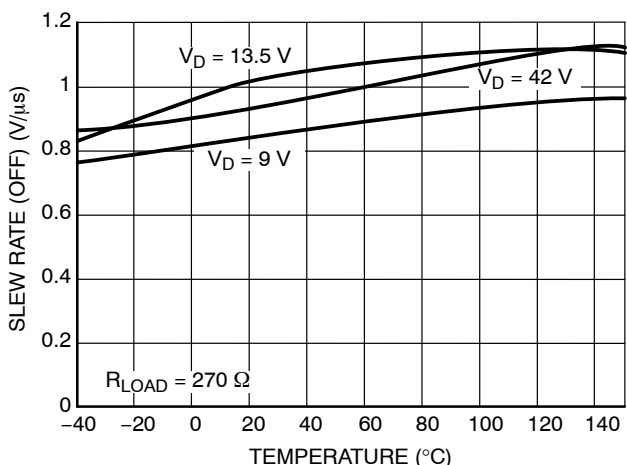


Figure 9. Slew Rate (OFF) vs. Temperature

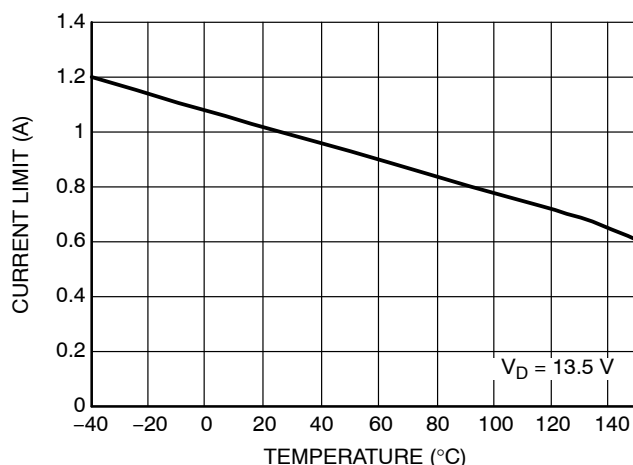


Figure 10. Current Limit vs. Temperature

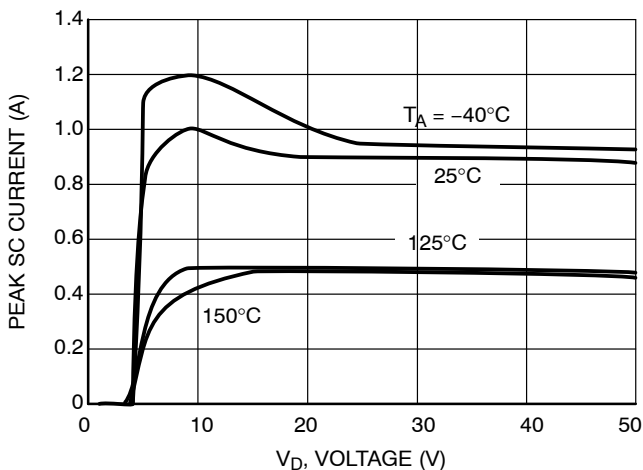


Figure 11. Peak Short Circuit Current vs. V_D Voltage

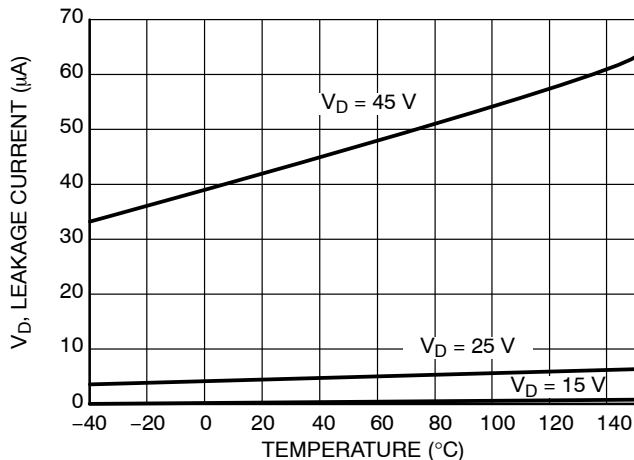


Figure 12. V_D Leakage Current vs. Temperature Off-State

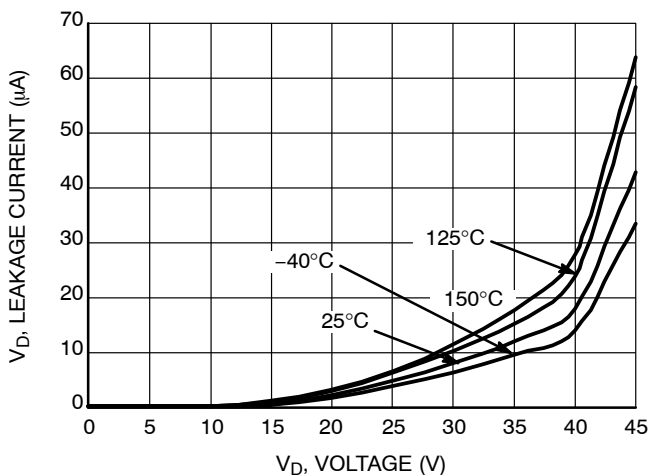


Figure 13. V_D Leakage Current vs. V_D Voltage Off-State

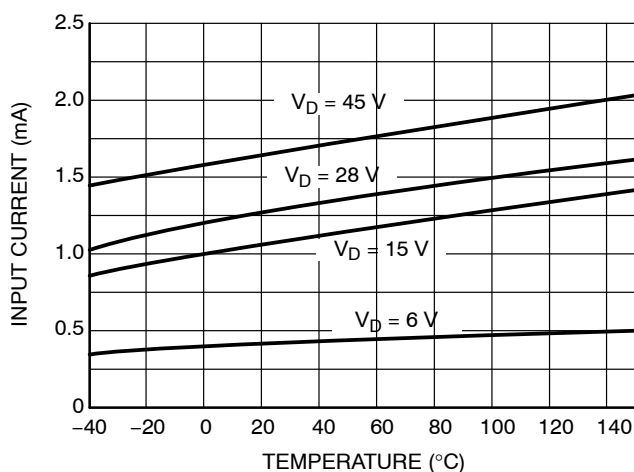


Figure 14. On-State Input Current vs. Temperature

TYPICAL CHARACTERISTIC CURVES

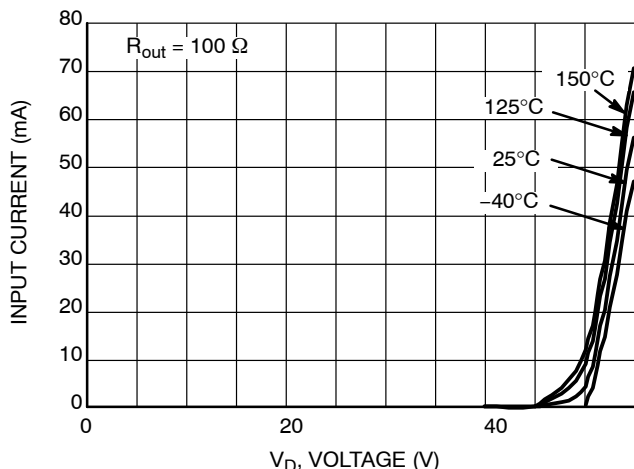


Figure 18. Input Current vs. V_D Voltage Off-State

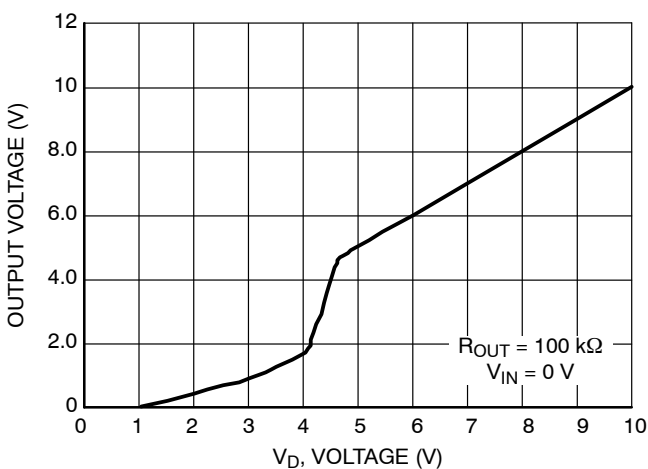


Figure 15. Output Voltage vs. V_D Voltage

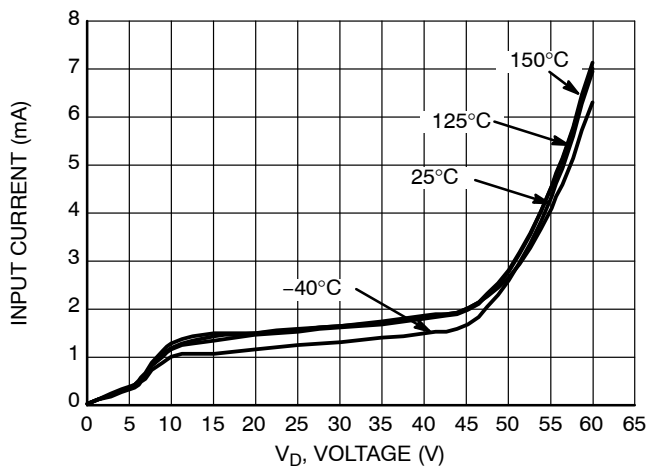


Figure 16. Input Current vs. V_D Voltage On-State

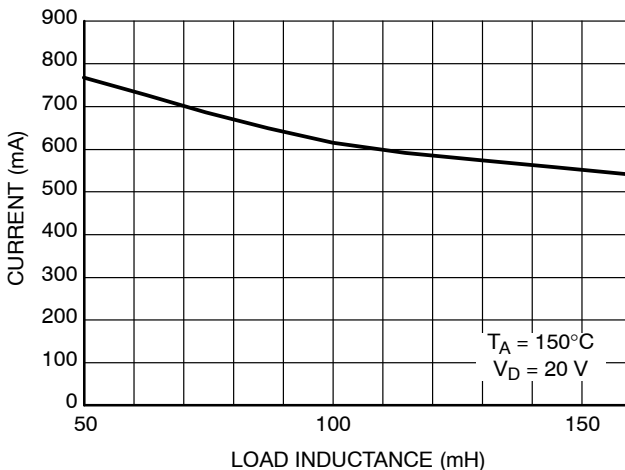


Figure 17. Single Pulse Maximum Switch-off Current vs. Load Inductance

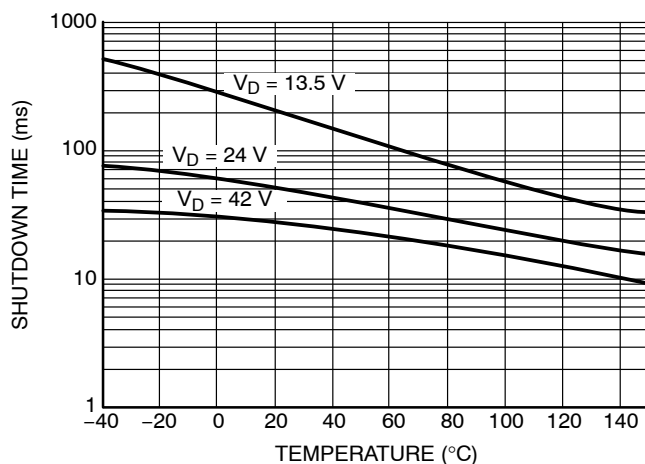


Figure 19. Initial Short-Circuit Shutdown Time vs. Temperature

NCV8450, NCV8450A

TYPICAL CHARACTERISTIC CURVES

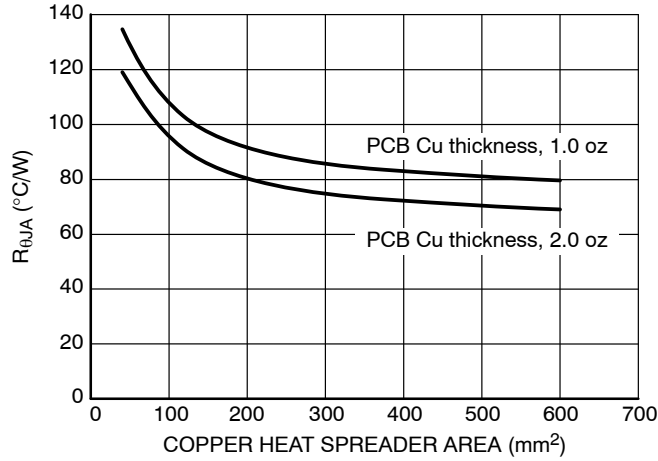


Figure 20. $R_{\theta JA}$ vs. Copper Area

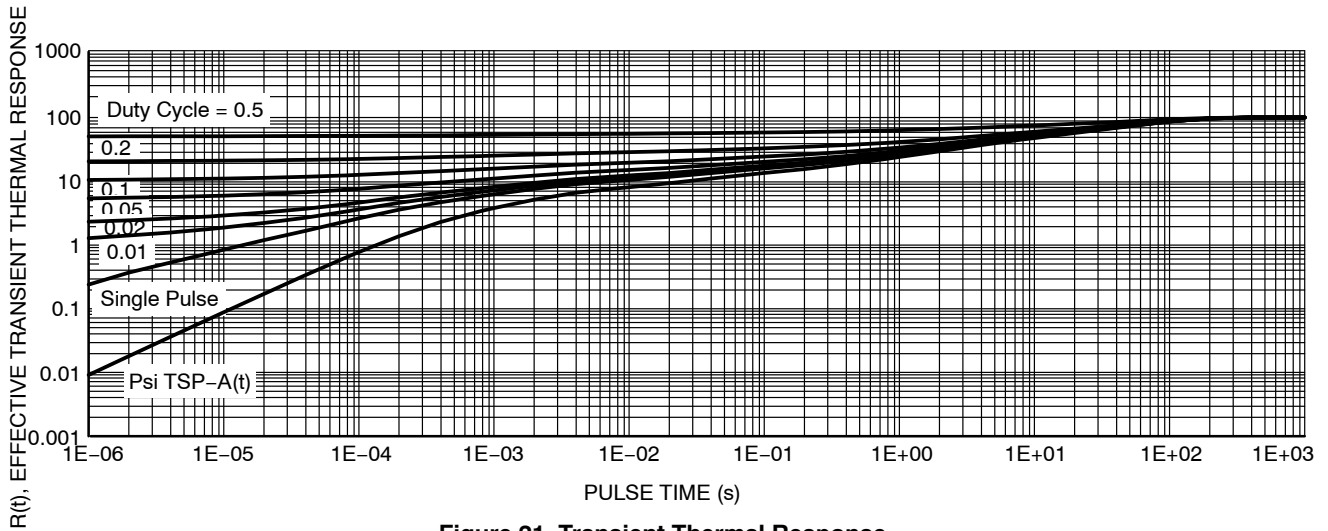


Figure 21. Transient Thermal Response

ISO PULSE TEST RESULTS

Test Pulse	Test Level	Test Results	Pulse Cycle Time and Generator Impedance
1	200 V	C	500 ms, 10 Ω
2	150 V	C	500 ms, 10 Ω
3a	200 V	C	100 ms, 50 Ω
3b	200 V	C	100 ms, 50 Ω
5	175 V	E(100 V)	400 ms, 2 Ω

ORDERING INFORMATION

Device	Package	Shipping [†]
NCV8450STT3G	SOT-223 (Pb-Free)	4000 / Tape & Reel
NCV8450ASTT3G	SOT-223 (Pb-Free)	4000 / Tape & Reel

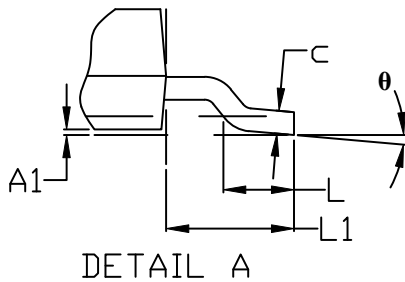
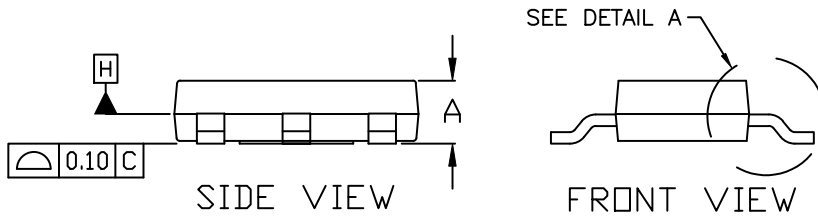
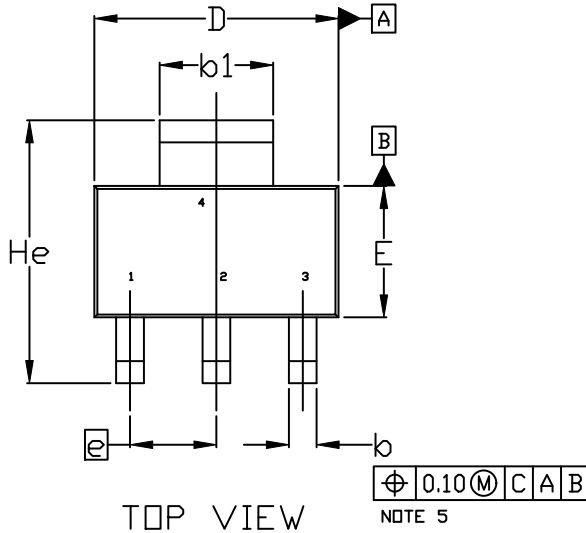
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



SCALE 1:1

SOT-223 (TO-261)
CASE 318E-04
ISSUE R

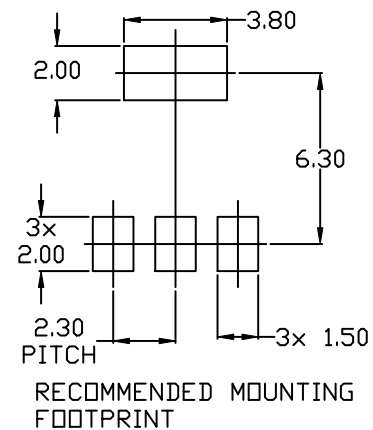
DATE 02 OCT 2018



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
4. DATUMS A AND B ARE DETERMINED AT DATUM H.
5. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
6. POSITIONAL TOLERANCE APPLIES TO DIMENSIONS b AND b1.

MILLIMETERS			
DIM	MIN.	NOM.	MAX.
A	1.50	1.63	1.75
A1	0.02	0.06	0.10
b	0.60	0.75	0.89
b1	2.90	3.06	3.20
c	0.24	0.29	0.35
D	6.30	6.50	6.70
E	3.30	3.50	3.70
e	2.30 BSC		
L	0.20	---	---
L1	1.50	1.75	2.00
He	6.70	7.00	7.30
θ	0°	---	10°



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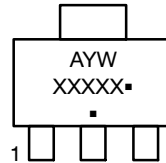
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SOT-223 (TO-261)
CASE 318E-04
ISSUE R

DATE 02 OCT 2018

- | | | | | |
|--|---|---|---|---|
| STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR | STYLE 2:
PIN 1. ANODE
2. CATHODE
3. NC
4. CATHODE | STYLE 3:
PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN | STYLE 4:
PIN 1. SOURCE
2. DRAIN
3. GATE
4. DRAIN | STYLE 5:
PIN 1. DRAIN
2. GATE
3. SOURCE
4. GATE |
| STYLE 6:
PIN 1. RETURN
2. INPUT
3. OUTPUT
4. INPUT | STYLE 7:
PIN 1. ANODE 1
2. CATHODE
3. ANODE 2
4. CATHODE | STYLE 8:
CANCELLED | STYLE 9:
PIN 1. INPUT
2. GROUND
3. LOGIC
4. GROUND | STYLE 10:
PIN 1. CATHODE
2. ANODE
3. GATE
4. ANODE |
| STYLE 11:
PIN 1. MT 1
2. MT 2
3. GATE
4. MT 2 | STYLE 12:
PIN 1. INPUT
2. OUTPUT
3. NC
4. OUTPUT | STYLE 13:
PIN 1. GATE
2. COLLECTOR
3. EMITTER
4. COLLECTOR | | |

**GENERIC
 MARKING DIAGRAM***



- A = Assembly Location
- Y = Year
- W = Work Week
- XXXXX = Specific Device Code
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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